MSCDC100H170AG

Datasheet

SiC Diode Full Bridge Power Module

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а <u> Міскосні</u>р company



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1 Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

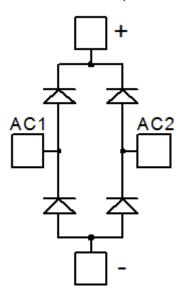
1.1 Revision 1.0

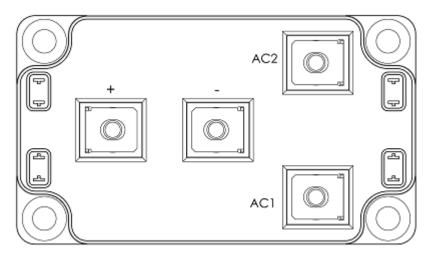
Revision 1.0 was published in December 2019. It is the first publication of this document.



2 Product Overview

This section shows the product overview of the MSCDC100H170AG device.





All ratings at Tj = 25 °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures should be followed.

2.1 Features

The following are key features of the MSCDC100H170AG device:

- Silicon Carbide (SiC) Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on VF



- High blocking voltage
- Low stray inductance
- M5 power connectors
- Aluminum nitride (AIN) substrate for improved thermal performance

2.2 Benefits

The following are benefits of the MSCDC100H170AG device:

- Outstanding performance at high frequency operation
- Low losses
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS compliant

2.3 Applications

The MSCDC100H170AG device is designed for the following applications:

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High-speed rectifiers



3 Electrical Specifications

This section shows the electrical specifications of the MSCDC100H170AG device.

3.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings per SiC diode of the MSCDC100H170AG device. **Table 1 • Absolute Maximum Ratings**

Symbol	Parameter		Max Ratings	Unit
V _{RRM}	Repetitive peak reverse voltage		1700	V
I _F	DC forward current	T _C = 125 °C	100	A

Table 2 • Thermal and Package Characteristics

Symbol	Characteristic			Min	Max	Unit	
V _{ISOL}	RMS isolation v 50 Hz/60 Hz	RMS isolation voltage, any terminal to case t =1 minute, 50 Hz/60 Hz				V	
Tj	Operating junc	Operating junction temperature range			175	°C	
T _{JOP}	Recommended conditions	Recommended junction temperature under switching conditions			T _{Jmax} –25		
T _{STG}	Storage tempe	Storage temperature range			125	_	
T _C	Operating case	Operating case temperature			125	_	
Torque	Mounting torque	To heatsink	M6	3	5	N.m	
	ion que	For terminals	M5	2	3.5		
Wt	Package weigh	Package weight			300	g	

3.2 Electrical Performance

The following table shows the thermal and package characteristics of the MSCDC100H170AG device.

Table 3 • Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _F	Diode forward voltage	I _F = 100 A	T _j = 25 °C		1.5	1.8	v
			T _j = 175 °C		2		
I _{RM}	Reverse leakage current	V _R = 1700 V	T _j = 25 °C		100	400	μΑ
			T _j = 175 °C		500		



Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Q _C	Total capacitive charge	V _R = 900 V		820		nC
с	Total capacitance	f = 1 MHz, V _R = 600 V		600		pF
		f = 1 MHz, V _R = 900 V		500		
R _{thJC}	Junction-to-case thermal resistance				0.174	°C/W



3.3 Typical Performance Curves

This section shows the typical performance curves of the MSCDC100H70AG device.

Figure 1 • Maximum Transient Thermal Impedance

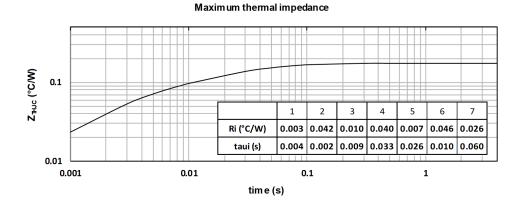


Figure 2 • Forward Current vs. Forward Voltage

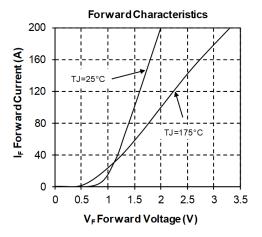
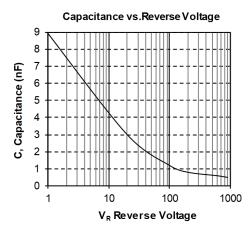


Figure 3 • Capacitance vs. Reverse Voltage





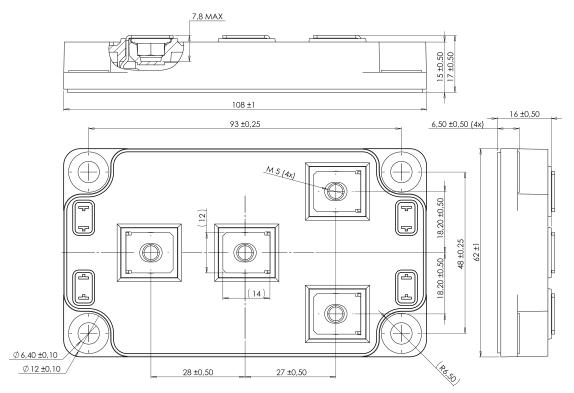
4 Package Specification

This section shows the package specifications for the MSCDC100H170AG device.

4.1 Package Outline Drawing

The following image illustrates the MSCDC100H170AG device. The dimensions in the following figure are in millimeters.

Figure 4 • Package Outline Drawing







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